

Surface Mount Schottky Barrier Rectifier

Reverse Voltage - 20 to 200 V

Forward Current - 2.0A

Features

- Metal silicon junction, majority carrier conduction
- For surface mounted applications
- Low power loss, high efficiency
- High forward surge current capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

MECHANICAL DATA

- Case: SOD-123FL
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 15mg 0.00048oz

PINNING

- 1 Cathode
2 Anode



Top View

Marking Code: DS22W ---S22
 DS24W ---S24
 DS26W ---S26
 DS28W ---S28
 DS210W ---S210
 DS212W ---S212
 DS215W ---S215
 DS220W ---S220

Simplified outline SOD-123FL and symbol

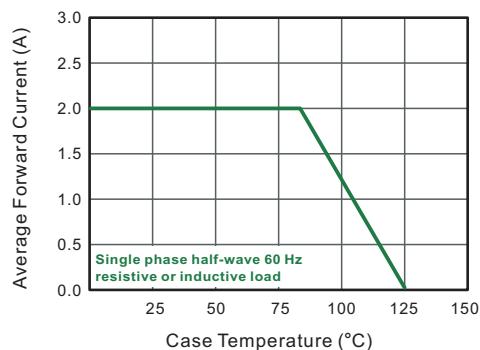
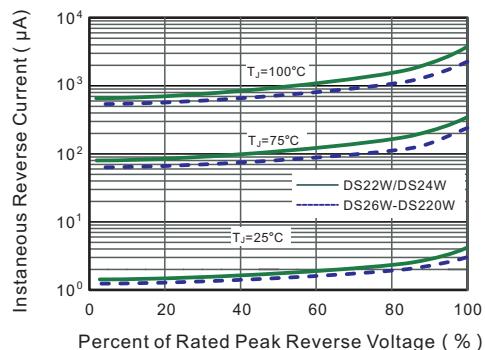
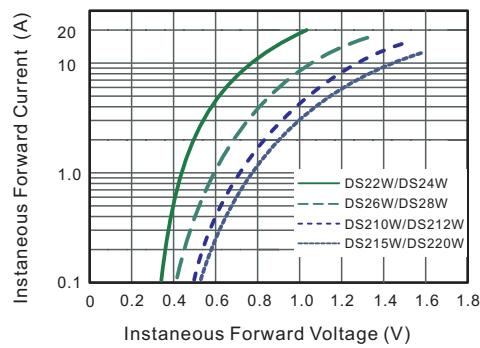
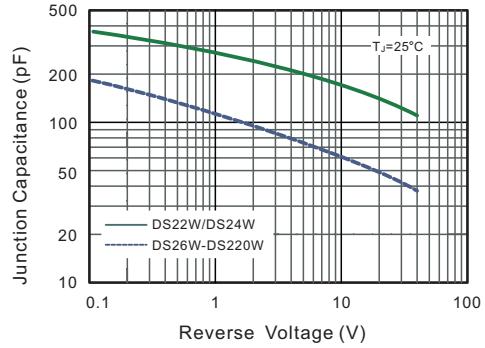
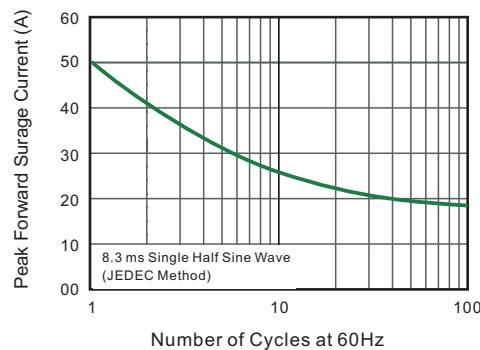
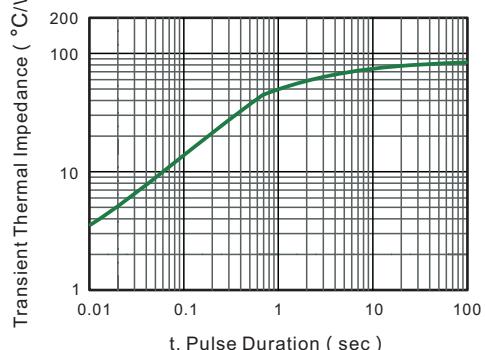
Absolute Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz resistive or inductive load, for capacitive load, derate by 20 %

Parameter	Symbols	DS22W	DS24W	DS26W	DS28W	DS210W	DS212W	DS215W	DS220W	Units						
Maximum Repetitive Peak Reverse Voltage	V _{RRM}	20	40	60	80	100	120	150	200	V						
Maximum RMS voltage	V _{RMS}	14	28	42	56	70	84	105	140	V						
Maximum DC Blocking Voltage	V _{DC}	20	40	60	80	100	120	150	200	V						
Maximum Average Forward Rectified Current	I _{F(AV)}	2.0								A						
Peak Forward Surge Current, 8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I _{FSM}	50								A						
Max Instantaneous Forward Voltage at 2 A	V _F	0.55		0.70		0.85		0.95		V						
Maximum DC Reverse Current T _a = 25°C at Rated DC Reverse Voltage T _a = 100°C	I _R	0.5 5			0.3 3											
Typical Junction Capacitance ⁽¹⁾	C _j	220		80						pF						
Typical Thermal Resistance ⁽²⁾	R _{θJA}	85								°C/W						
Operating Junction Temperature Range	T _j	-55 ~ +125								°C						
Storage Temperature Range	T _{stg}	-55 ~ +150								°C						

(1) Measured at 1 MHz and applied reverse voltage of 4 V D.C

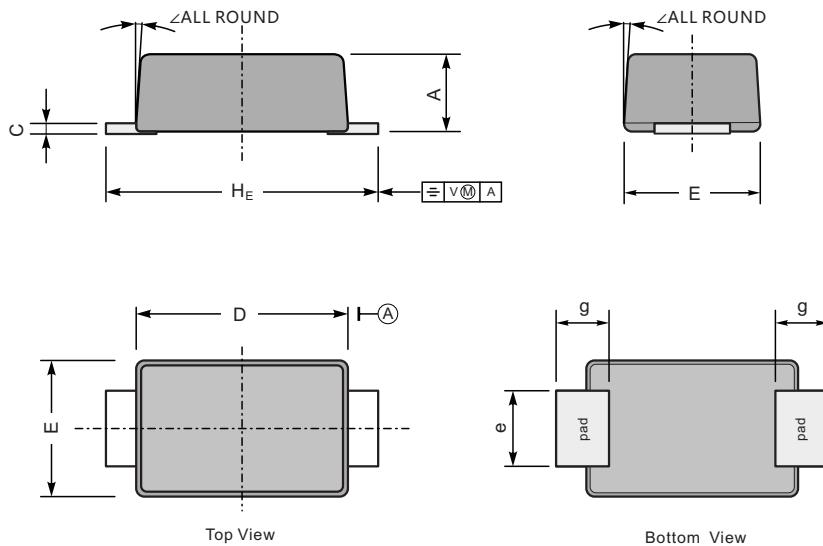
(2) P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.

Fig.1 Forward Current Derating Curve**Fig.2 Typical Reverse Characteristics****Fig.3 Typical Forward Characteristic****Fig.4 Typical Junction Capacitance****Fig.5 Maximum Non-Repetitive Peak Forward Surge Current****Fig.6- Typical Transient Thermal Impedance**

PACKAGE OUTLINE

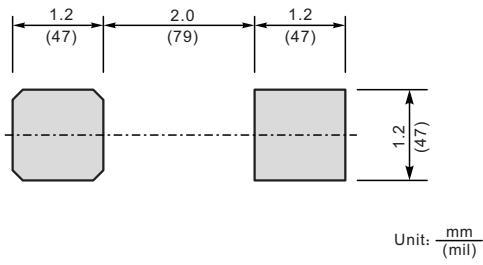
Plastic surface mounted package; 2 leads

SOD-123FL



UNIT		A	C	D	E	e	g	H_E	\angle
mm	max	1.1	0.20	2.9	1.9	1.1	0.9	3.8	7°
	min	0.9	0.12	2.6	1.7	0.8	0.7	3.5	
mil	max	43	7.9	114	75	43	35	150	7°
	min	35	4.7	102	67	31	28	138	

The recommended mounting pad size



Marking

Type number	Marking code
DS22W	S22
DS24W	S24
DS26W	S26
DS28W	S28
DS210W	S210
DS212W	S212
DS215W	S215
DS220W	S220

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